



P-Channel 30-V (D-S) MOSFET

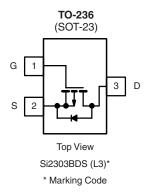
PRODUCT SUMMARY			
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A) ^b	
- 30	0.200 at V _{GS} = - 10 V	- 1.64	
	0.380 at V _{GS} = - 4.5 V	- 1.0	

FEATURES

• Halogen-free Option Available







Ordering Information: Si2303BDS-T1

Si2303BDS-T1-E3 (Lead (Pb)-free)

Si2303BDS-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS T	_A = 25 °C, unle	ss otherwise r	noted			
Parameter		Symbol	5 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	- 30		V	
Gate-Source Voltage		V _{GS}	± 20			
Continuous Dunin Courset /T 450 °C\b	T _A = 25 °C	- I _D	- 1.64	- 1.49		
Continuous Drain Current (T _J = 150 °C) ^b	T _A = 70 °C		- 1.31	- 1.2		
Pulsed Drain Current ^a		I _{DM}	- 10		Α	
Continuous Source Current (Diode Conduction) ^b		I _S	- 0.75	- 0.6		
Davis Diadratical	T _A = 25 °C	- P _D	0.9	0.7	W	
Power Dissipation ^b	T _A = 70 °C		0.57	0.45		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient ^b	- R _{thJA}	120	145	°C/W	
Maximum Junction-to-Ambient ^c	' 'thJA	140	175]	

Notes:

- a. Pulse width limited by maximum junction temperature.
- b. Surface Mounted on FR4 board, $t \le 5 \text{ s.}$
- c. Surface Mounted on FR4 board.

For SPICE model information via the Worldwide Web: http://www.vishay.com/www/product/spice.htm

* Pb containing terminations are not RoHS compliant, exemptions may apply.

Si2303BDS

Vishay Siliconix



SPECIFICATIONS T _J = 25 °C, unless otherwise noted							
			Limits				
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0 \text{ V}, I_D = -10 \mu\text{A}$	- 30			V	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 1.0		- 3.0]	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
Zava Cata Valtaga Dvain Current	1	V _{DS} = - 30 V, V _{GS} = 0 V			- 1	μА	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			- 10		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \le -5 \text{ V}, V_{GS} = -10 \text{ V}$	- 6			Α	
5	В	$V_{GS} = -10 \text{ V}, I_D = -1.7 \text{ A}$		0.150	0.200		
Drain-Source On-Resistance ^a	R _{DS(on)}	$V_{GS} = -4.5 \text{ V}, I_D = -1.3 \text{ A}$		0.285	0.380	Ω	
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 5 V, I _D = - 1.7 A		2.0		S	
Diode Forward Voltage	V_{SD}	I _S = - 0.75 A, V _{GS} = 0 V		- 0.85	- 1.2	٧	
Dynamic ^b							
Total Gate Charge	Q_g			4.3	10	nC	
Gate-Source Charge	Q _{gs}	V_{DS} = - 15 V, V_{GS} = - 10 V, $I_D \cong$ - 1.7 A		0.8			
Gate-Drain Charge	Q_{gd}			1.3		1	
Input Capacitance	C _{iss}			180		pF	
Output Capacitance	C _{oss}	V _{DS} = - 15 V, V _{GS} = 0 V, f = 1 MHz		50			
Reverse Transfer Capacitance	C _{rss}			35		1	
Switching ^c					•		
Turn-On Time	t _{d(on)}	V 45V B 450		55	80		
ium-on iime	t _r	$V_{DD} = -15 \text{ V}, R_L = 15 \Omega$ $I_D \cong -1.0 \text{ A}, V_{GEN} = -4.5 \text{ V}$		40	60		
Turn-Off Time	t _{d(off)}	$R_{G} = 6 \Omega$		10	20	ns	
Turr-Oil Tillie	t _f	a		10	20		

Notes:

- a. Pulse test: PW \leq 300 $\mu s,$ duty cycle \leq 2 %.
- b. For DESIGN AID ONLY, not subject to production testing.
- c. Switching time is essentially independent of operating temperature.

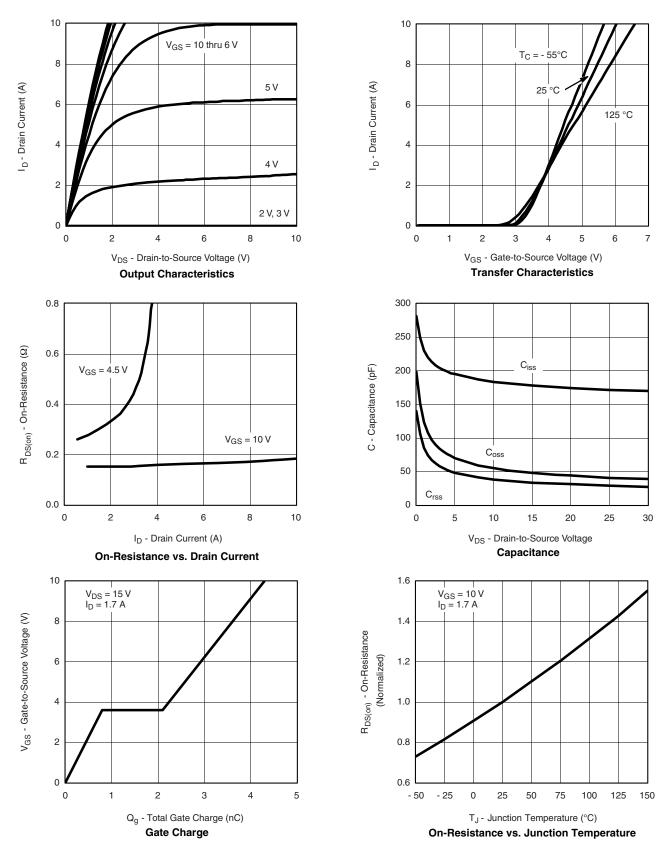
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.







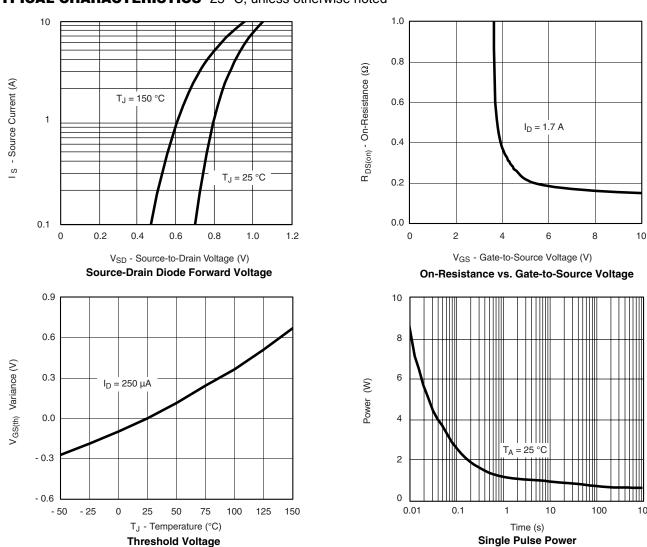
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

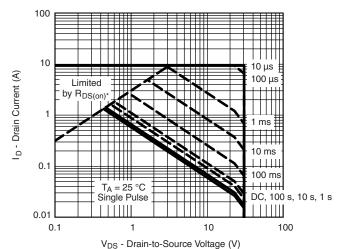


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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



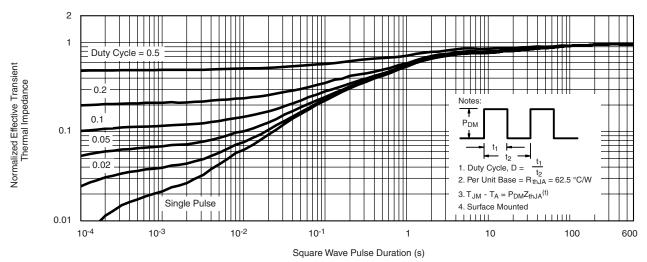


Safe Operating Area, Junction-to-Case

1000



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Ambient

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?72065.



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